Certificate TW17/01039

The management system of

SGS

Innodisk Corporation

3F, 4F, 5F, No. 237, Sec. 1, Datong Rd., Xizhi District, New Taipei City 221, Taiwan, R.O.C.

has been assessed and certified as meeting the requirements of

ISO 14001:2015

For the following activities

Design and manufacture of flash memory, DRAM (Dynamic Random-Access Memory) module, embedded peripherals and AloT (Artificial Intelligence of Things) products.

This certificate is valid from 29 September 2023 until 29 September 2026 and remains valid subject to satisfactory surveillance audits. Issue 4. Certified since 02 February 2012

Certified activities performed by additional sites are listed on subsequent pages.

Jorothan M. Hell

Authorised by Jonathan Hall

Global Head - Certification Services

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Rossmore Business Park, Ellesmere Port, Cheshire, CH65 3EN, UK t +44 (0)151 350-6666 - www.sqs.com







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Certificate TW17/01039, continued

Innodisk Corporation



ISO 14001:2015

Issue 4

Sites

Innodisk Corporation

3F, 4F, 5F, No. 237, Sec. 1, Datong Rd., Xizhi District, New Taipei City 221, Taiwan, R.O.C.

Design and manufacture of flash memory, DRAM (Dynamic Random-Access Memory) module, embedded peripherals and AloT (Artificial Intelligence of Things) products.

Innodisk Corporation HQ

3F, 4F, 5F, No. 237, Sec. 1, Datong Rd., Xizhi District, New Taipei City 221, Taiwan, R.O.C.

Design and manufacture of flash memory, DRAM (Dynamic Random-Access Memory) module, embedded peripherals and AloT (Artificial Intelligence of Things) products.

Innodisk Corporation Yilan

Yilan: No. 128, Yike Rd., Yilan City, Yilan County 260, Taiwan, R.O.C.

Manufacture of flash memory, DRAM (Dynamic Random-Access Memory) module, embedded peripherals and AloT (Artificial Intelligence of Things) products.









